M3e

The Mu3e Detector and prototyping and tooling for the Mu3e vertex detector

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Forum on Tracking Detector Mechanics
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Overview

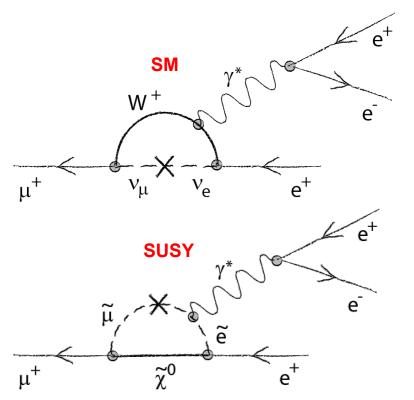


- Physics motivation
- Experimental challenges
- Experiment features
 - Sensor
 - Mechanics
 - Connections
 - Cooling
- Production and tooling
- Mock-up tests
 - Silicon Heater

Mu3e: Physics Motivation

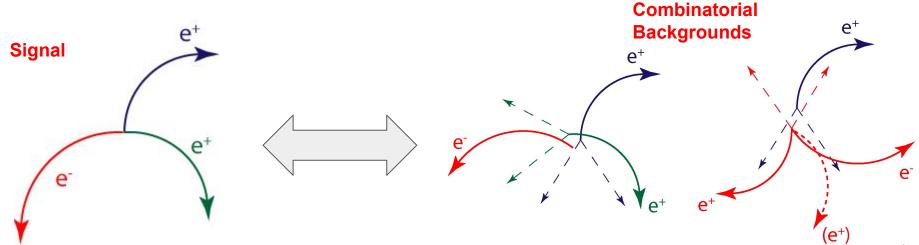


- Search for µ→eee
 - Standard Model: BR (μ → eee) < 10⁻⁵⁴
- New physics might enhance BR
- Current limit:
 - BR (μ → eee) < 10⁻¹² (SINDRUM, 1988)
- Aimed single-event sensitivity:
 - BR (μ → eee) < 2 · 10⁻¹⁵ (Phase 1)
 - BR (μ → eee) < 10⁻¹⁶ (Phase 2)
- PSI High Intensity Muon Beamline
- Phase 1 construction starting by the end of the year



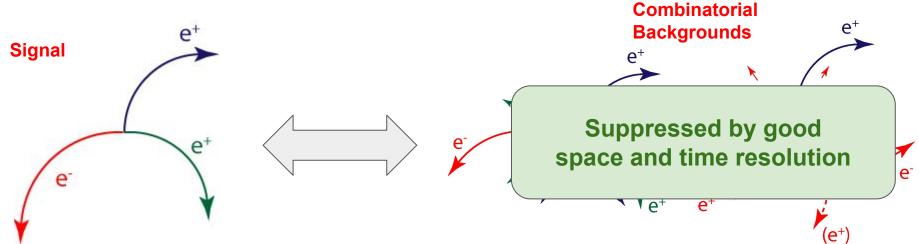


- Tracking electrons coming from muon decays
- High muon rates
 - o 10⁸ Hz Phase I
 - 10⁹ Hz Phase II



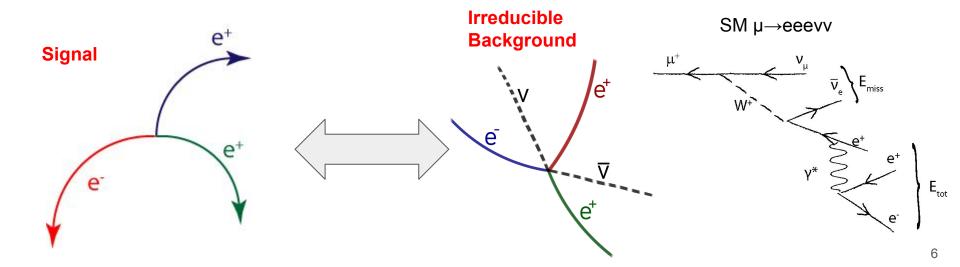


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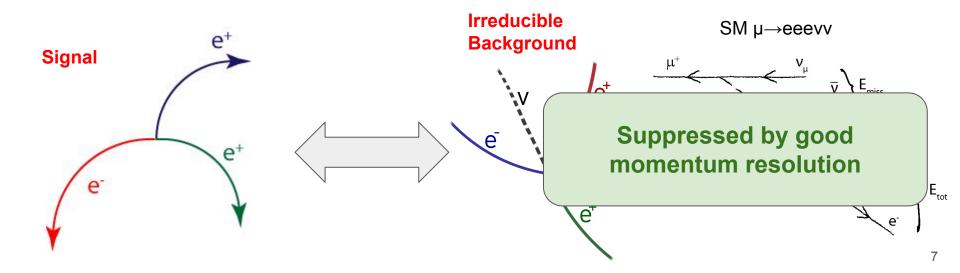


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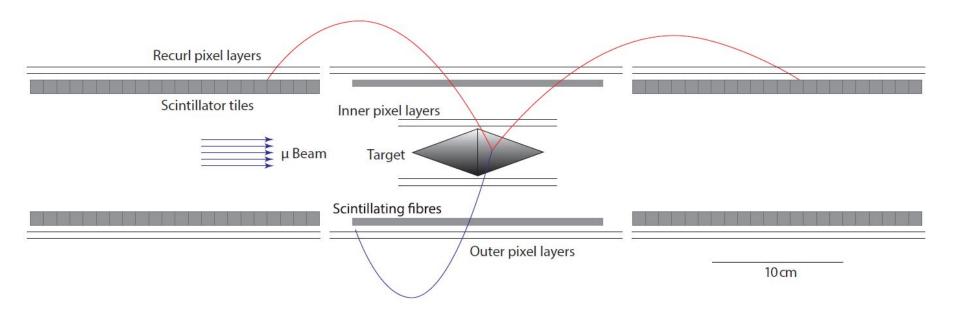


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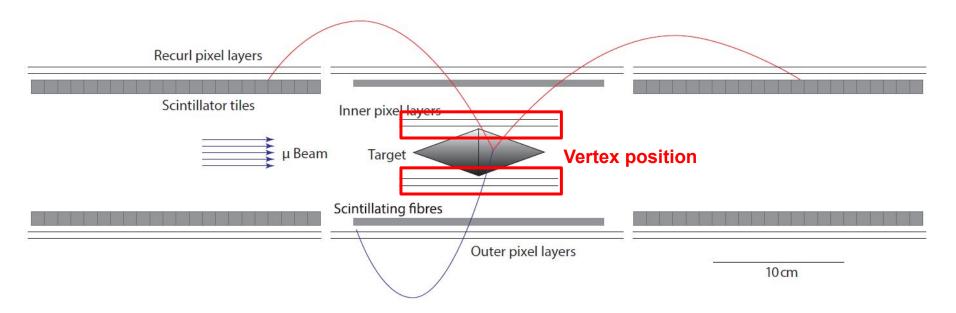


- Tracking electrons coming from muon decays
- Magnetic field (1 T)



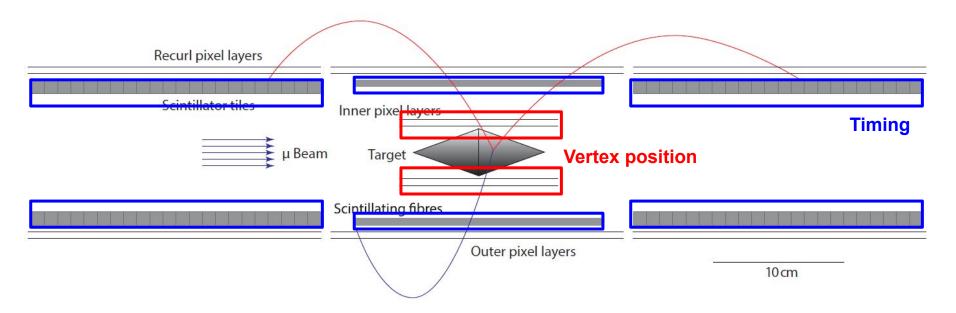


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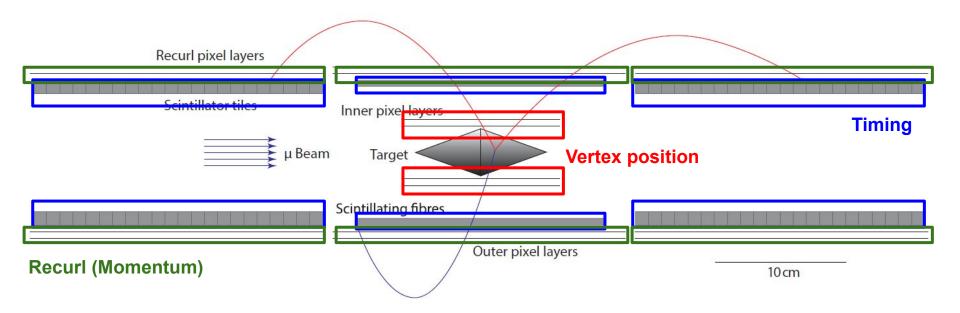


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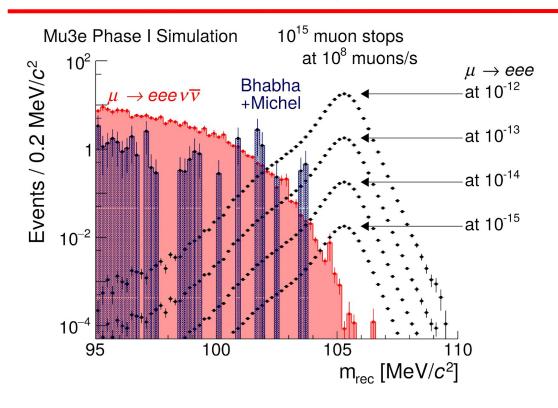




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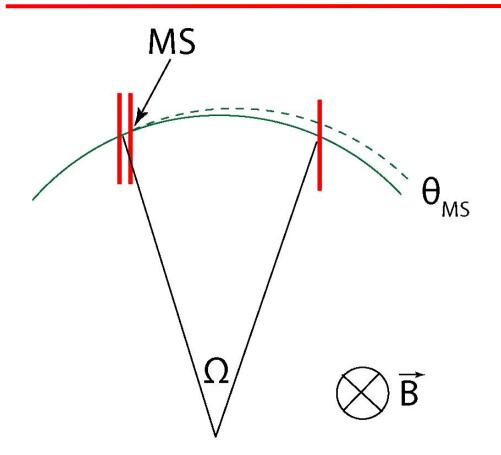




Momentum resolution crucial for detecting the peak at muon mass...

Invariant mass of signal decay, radiative decay and accidental background (Bhaba+Michel) [Mu3e TDR]

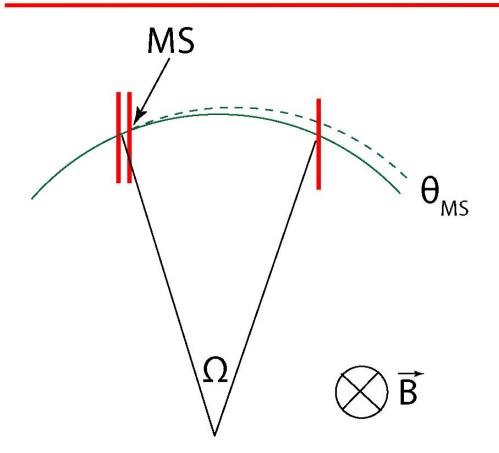




Electron energy very low (< 53 MeV)

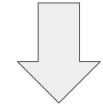
Multiple scattering main factor to momentum resolution





Electron energy very low (< 53 MeV)

Multiple scattering main factor to momentum resolution

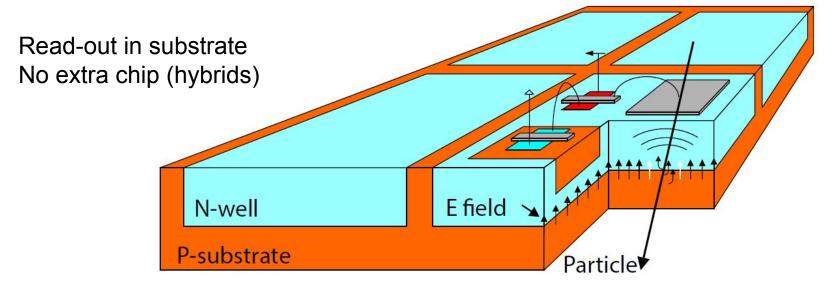


Material budget minimization is the key factor



Reduce silicon thickness of tracker

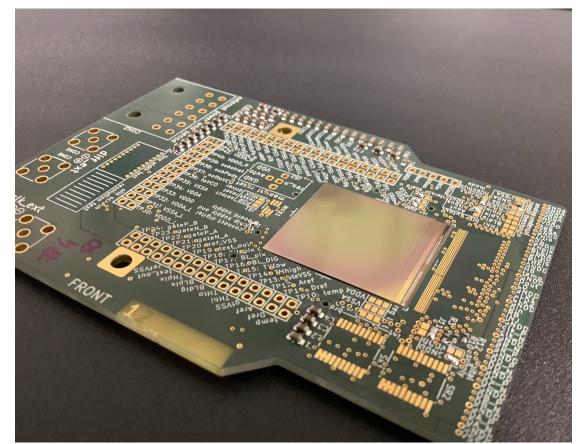
HV-CMOS sensors



HV allows for high speed and efficiency

Mupix10





First full-scale prototype

256x250 pixels, 80x80 μm² size

Final sensor Mupix11 -expected in Autumn

Specifications:

- ~ 2x2 cm² active matrix
- Efficiency > 99 %
- Time resolution < 20 ns
- Thinned to 50 μ m (X/X₀= 0.054 %)



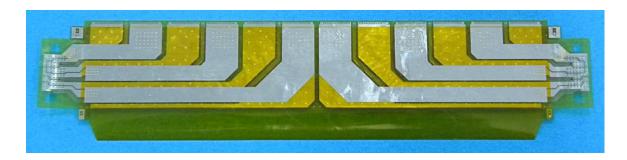
Kapton aluminum flexes for

- Support structure
- Electrical connections

Al 14 μm PI 10 μm Glue 5 µm PI 25 μm Glue 5 µm Al 14 μm PI 10 μm

Cross section

High Density Interconnects HDIs

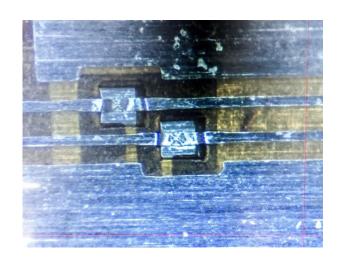


Example Produced by LTU (Ukraine)



Connections

Pixels to ladders

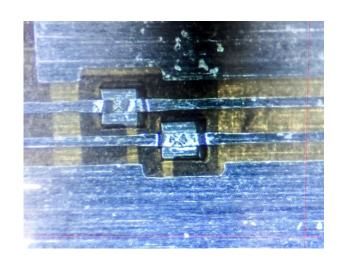


SpTAB bonds (Singe Point Tape Automated Bonding)



Connections

Pixels to ladders



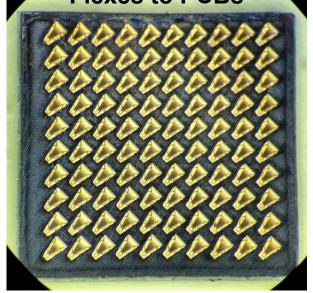
No extra material No wires

SpTAB bonds (Singe Point Tape Automated Bonding)



Connections

Ladders to flexes Flexes to PCBs



Gold ball interposers



Connections

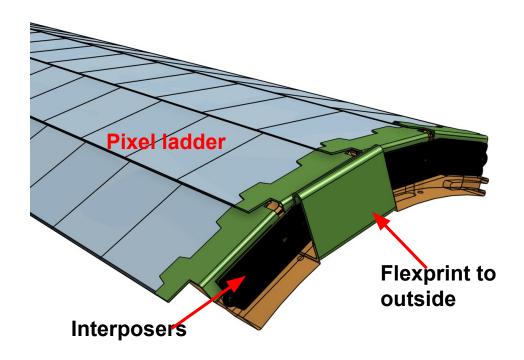
Ladders to flexes
Flexes to PCBs



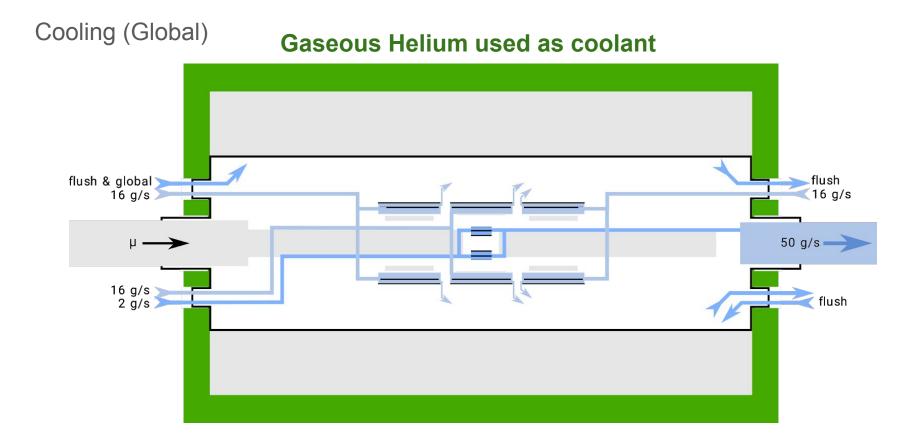
Connected via screws
Easy to attach/remove
Modularity
Compactness



Gold ball interposers

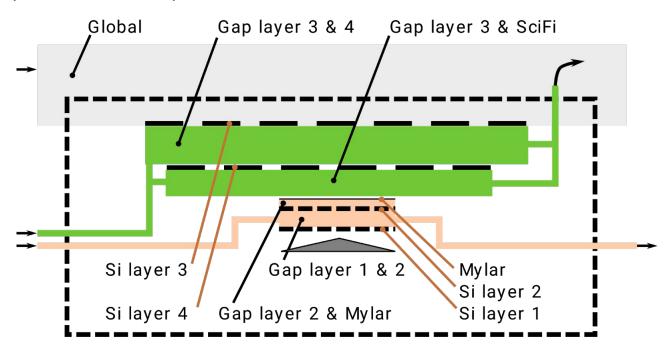






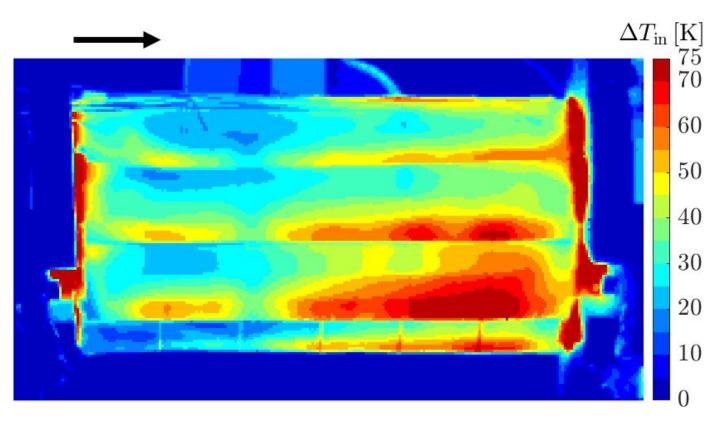


Cooling (Pixels detailed)



Temperature < 70° (glass-transition temperature of the adhesives)





Simulations: 70 K of ΔT with 400 mW/cm² power consumption (double the nominal)

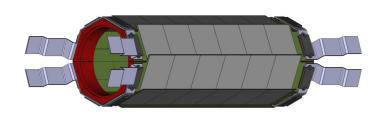


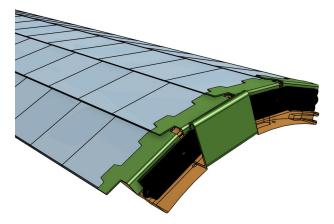
Inner layers:

- In central station around target
- 2 layers with 8/10 ladders
- 6 chips per ladder

Outer layers:

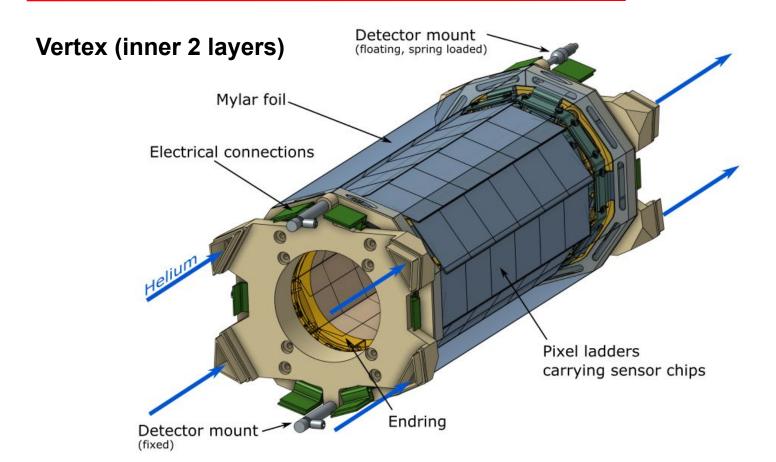
- 3 stations
- 2 layers with 24/28 ladders
- 17/18 chips per ladder





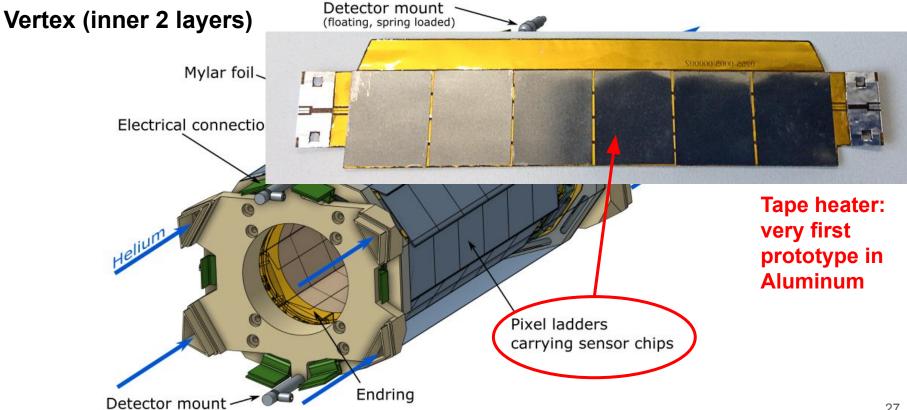
Total material budget per layer: 0.115% X/X₀



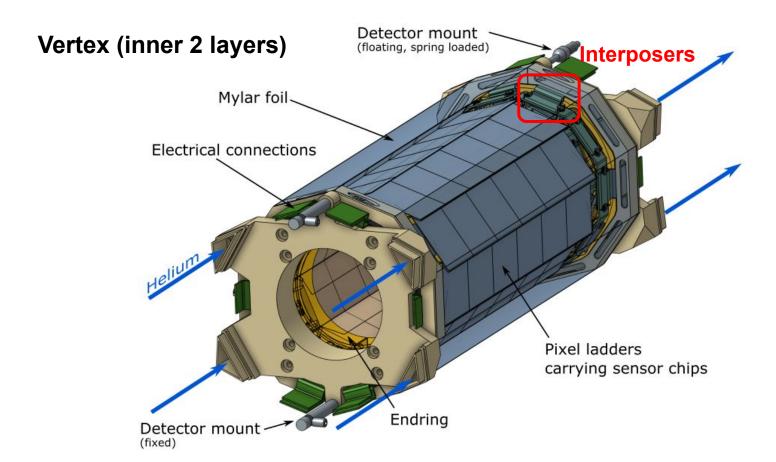


(fixed)

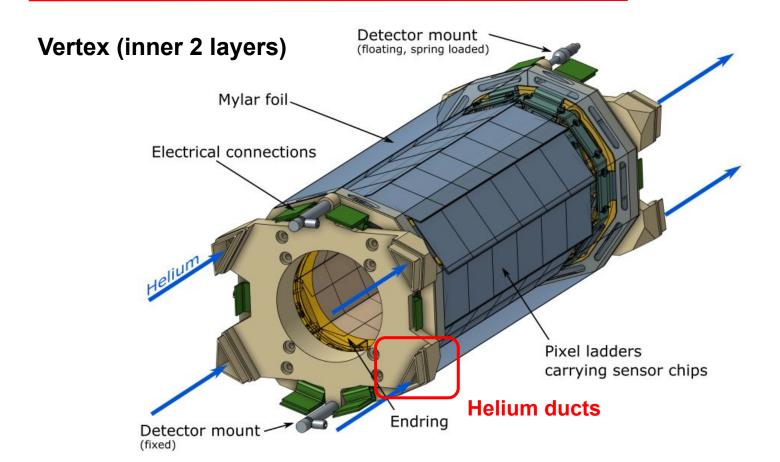








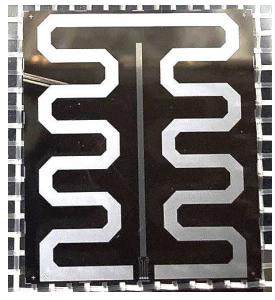






Prototype: Silicon heater

- Prototype made of
 - 50 μm thin silicon heaters with a
 - $\sim 1.2 \text{ k}\Omega$ resistive thermometer
 - High-density interconnects from LTU (same technology as final detector)
- Perfect matching of geometry and material
- Construction proved that specification can be met:
 - Final chip placement precision of 5 μm (along beam direction)
 - Glue thickness ≈ 5 μm
 - Electrical connections via spTAB established



Silicon heater chip

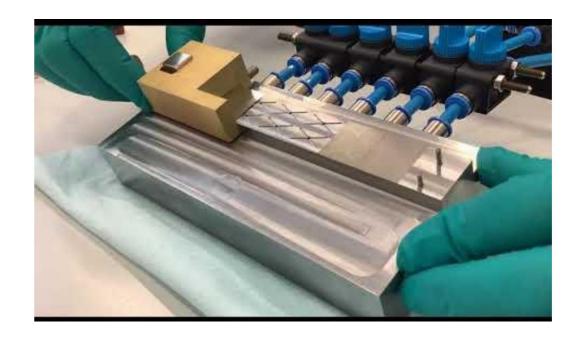


Vertex (inner 2 layers)

Chips placed by hand on vacuum structure

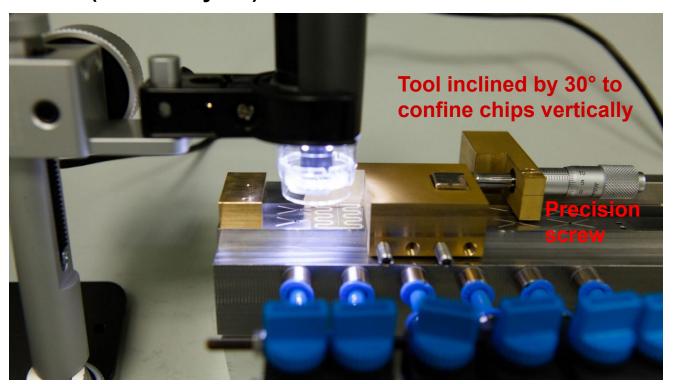
Each chip position has dedicated vacuum channel

(67) Mounting Tool Prototype for Layer 1/2 (Mu3e) - YouTube





Vertex (inner 2 layers)



Accuracy required: 5 µm



Vertex (inner 2 layers)

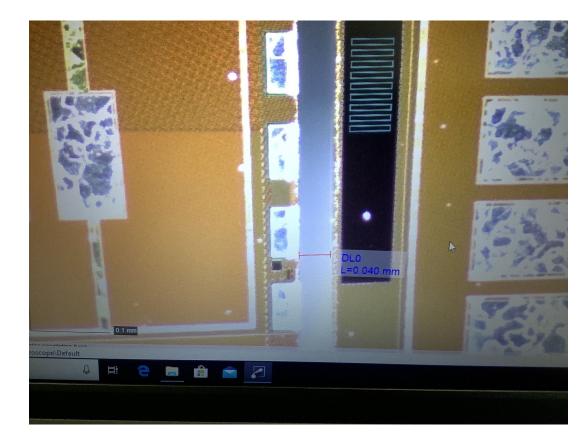
Chip relative position controlled by microscope (1.5 µm resolution)





Vertex (inner 2 layers)

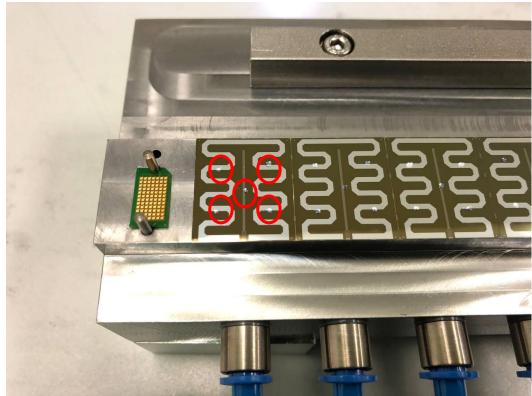
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Vertex (inner 2 layers)

Glue deposited

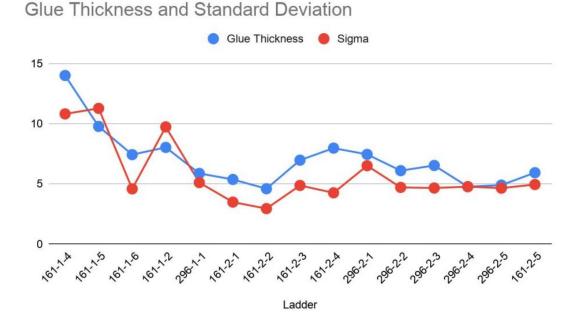




Vertex (inner 2 layers)

Glue deposited

Thickness of 5 µm achieved after few trials

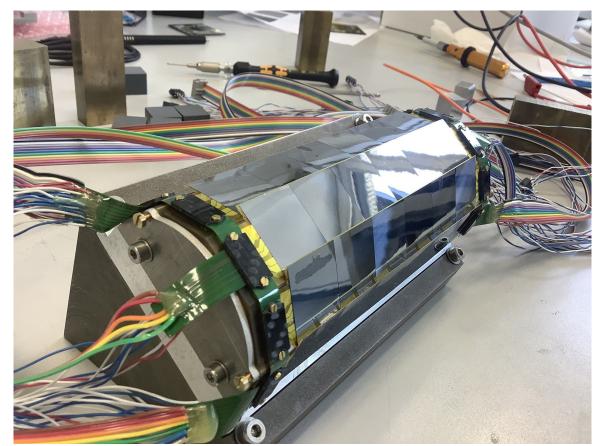


Production



Vertex (inner 2 layers)

Ladders mounted together on the support structures (half-layers)



Production



Vertex (inner 2 layers)

Check of connections

Quick heating and thermal camera



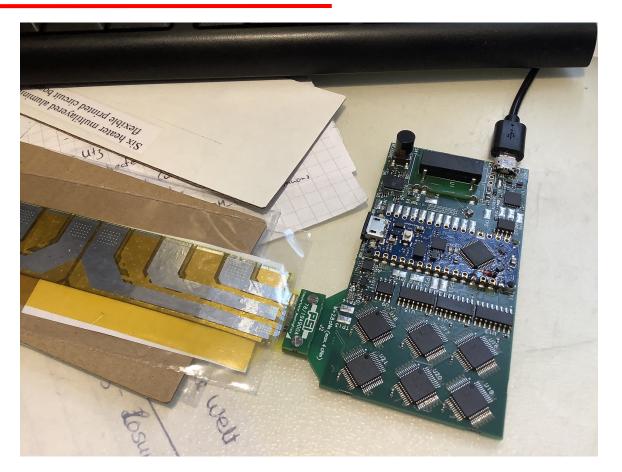
Production



Vertex (inner 2 layers)

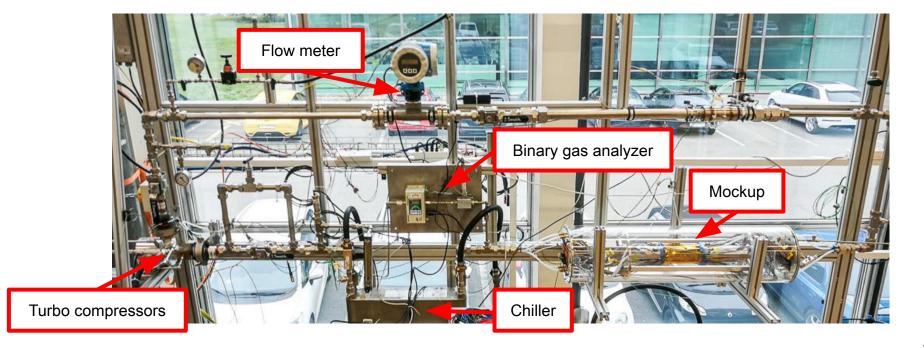
Check of connections

Board to compute resistivity between channels





Test stand for vertex tracker cooling at FHNW Brugg/Windisch



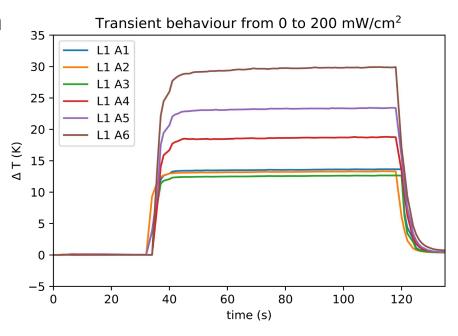


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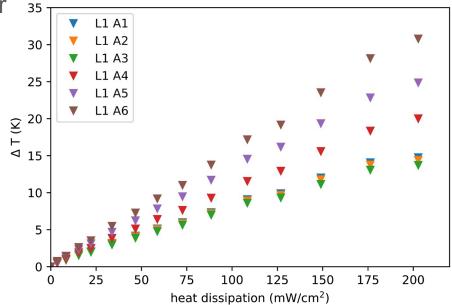


- Temperature measured for 6 sensor on one inner ladder
- Silicon heater prototype operated at nominal heat load of 200 mW/cm²
- Equilibrium reached in seconds
- Maximum allowed temperature is 70°C
- Maximum ΔT ~ 30 K
 (foreseen inlet temperature ~ 5°C)





- Measurement of temperature-to-power relation
- Temperature difference linearly depending on heat dissipation
- Expected ΔT < 70 K for 400 mW/cm² (conservative limit)
- Cooling concept works
- More detailed studies to come

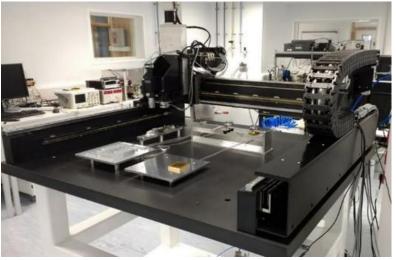


Outer pixel layers production



Performed in Oxford.





Automatized process
Gantry: chip absolute position with high precision

Conclusions



- Mu3e will investigate non-SM decays
- Several challenges in pixel tracker design
 - Material budget minimization
 - Compactness
- Construction will begin at the end of the year
- Production flow for inner layers tested with prototypes
 - Silicon heater: same thermo-mechanical properties as final detector
 - Helium cooling
 - Promising results
- Looking forward to start production!

Bonus



Testbeam at PSI on muon beamline (14/06)





Bonus



Testbeam at PSI on muon beamline (14/06)



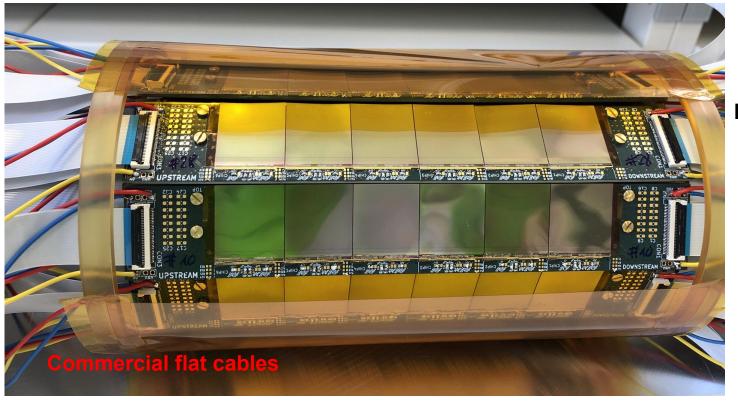
Pixel detector

- Mupix10, 50 μm thin
- Glued on kapton-aluminum flex (same as final detector)
- Mounted on PCB
 - Mupix10 need extra single-ended lines
 - HDIs cannot be used
 - Reduced angular acceptance
- First time operating 6 chips together

Bonus



Testbeam at PSI on muon beamline (14/06)



Pixel detector